onsemi

High- and Low-Side Gate Driver

FAN7842

Description

The FAN7842, a monolithic high and low side gate drive IC, which can drive MOSFETs and IGBTs that operate up to +200 V.

onsemi's high–voltage process and common–mode noise canceling technique provide stable operation of the high–side driver under high–dv/dt noise circumstances. An advanced level–shift circuit allows high–side gate driver operation up to $V_S = -9.8$ V (typical) for $V_{BS} = 15$ V. The input logic level is compatible with standard TTL–series logic gates.

The UVLO circuits for both channels prevent malfunction when V_{CC} and V_{BS} are lower than the specified threshold voltage. Output driver current (source/sink) is typically 350 mA/650 mA, respectively.

Features

- Floating Channels Designed for Bootstrap Operation to +200 V
- Typically 350 mA/650 mA Sourcing/Sinking Current Driving Capability for Both Channels
- Common-Mode dv/dt Noise Canceling Circuit
- Extended Allowable Negative V_S Swing to -9.8 V for Signal Propagation at V_{CC} = V_{BS} = 15 V
- V_{CC} & V_{BS} Supply Range from 10 V to 20 V
- UVLO Functions for Both Channels
- TTL Compatible Input Logic Threshold Levels
- Matched Propagation Delay Below 50 ns
- Output In-phase with Input Signal
- This Device is Pb-Free, Halide Free and is RoHS Compliant

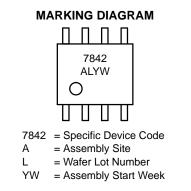
Applications

- Battery Based Motor Applications (E-bike, Power Tool)
- Telecom DC–DC Converter

Related Resources

- <u>AN-6076</u> Design and Application Guide of Bootstrap Circuit for High–Voltage Gate–Drive IC
- <u>AN-9052</u> Design Guide for Selection of Bootstrap Components
- <u>AN-8102</u> Recommendations to Avoid Short Pulse Width Issues in HVIC Gate Driver Applications





ORDERING INFORMATION

See detailed ordering and shipping information on page 11 of this data sheet.

1

TYPICAL APPLICATION CIRCUIT

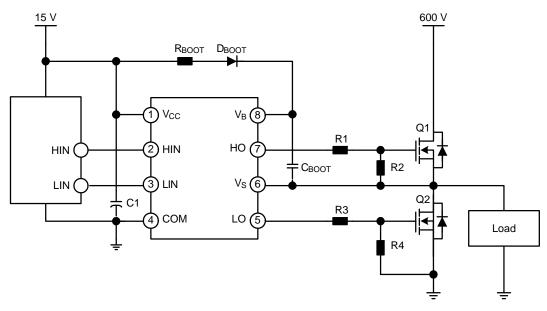


Figure 1. Application Circuit for Half-Bridge



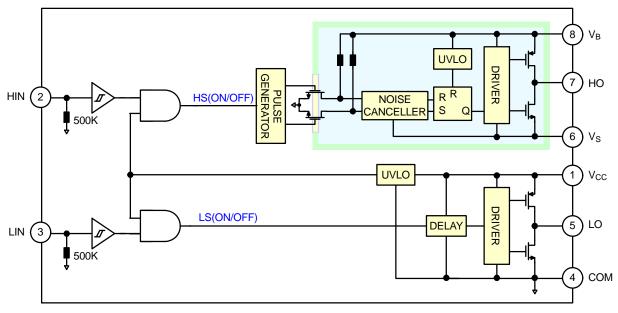


Figure 2. Functional Block Diagram

PIN ASSIGNMENTS

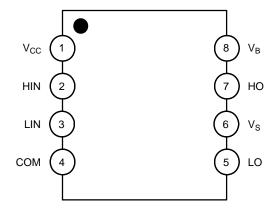


Figure 3. Pin Configuration (Top View)

PIN DEFINITIONS

| Name | Description | |
|-----------------|--|--|
| V _{CC} | Low-Side Supply Voltage | |
| HIN | Logic Input for High-Side Gate Driver Output | |
| LIN | Logic Input for Low–Side Gate Driver Output | |
| СОМ | gic Ground and Low-Side Driver Return | |
| LO | ow-Side Driver Output | |
| VS | High–Voltage Floating Supply Return | |
| HO | High-Side Driver Output | |
| V _B | High–Side Floating Supply | |

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Min | Мах | Unit |
|--|---|----------------------|-----------------------|------|
| VS | High-side Offset Voltage | V _B – 25 | V _B + 0.3 | V |
| V _B | High-side Floating Supply Voltage | -0.3 | 225 | |
| V _{HO} | High-side Floating Output Voltage HO | V _S – 0.3 | V _B + 0.3 | |
| V _{CC} | Low-side and Logic Fixed Supply Voltage | -0.3 | 25 | |
| V _{LO} | Low-side Output Voltage LO | -0.3 | V _{CC} + 0.3 | |
| V _{IN} | Logic Input Voltage (HIN, LIN) | -0.3 | V _{CC} + 0.3 | |
| СОМ | Logic Ground | V _{CC} – 25 | V _{CC} + 0.3 | |
| dV _S /dt | Allowable Offset Voltage Slew Rate | - | 50 | V/ns |
| P _D (Note 1) (Note 2) (Note 3) | Power Dissipation | - | 0.625 | W |
| θ_{JA} | Thermal Resistance, Junction-to-ambient | - | 200 | °C/W |
| TJ | Junction Temperature | - | 150 | °C |
| T _{STG} | Storage Temperature | - | 150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Mounted on 76.2 x 114.3 x 1.6 mm PCB (FR-4 glass epoxy material).

2. Refer to the following standards:

JESD51–2: Integral circuits thermal test method environmental conditions – natural convection

JESD51-3: Low effective thermal conductivity test board for leaded surface mount packages

3. Do not exceed P_D under any circumstances.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Min | Max | Unit |
|-----------------|--|---------------------|---------------------|------|
| VB | High-side Floating Supply Voltage | V _S + 10 | V _S + 20 | V |
| Vs | High-side Floating Supply Offset Voltage | 6 – V _{CC} | 200 | |
| V _{HO} | High-side (HO) Output Voltage | VS | VB | |
| V _{LO} | Low-side (LO) Output Voltage | COM | V _{CC} | |
| V _{IN} | Logic Input Voltage (HIN, LIN) | COM | V _{CC} | |
| V _{CC} | Low-side Supply Voltage | 10 | 20 | |
| T _A | Ambient Temperature | -40 | 125 | °C |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

| Symbol | Characteristics | Test Condition | Min | Тур | Max | Unit |
|--|---|---|-----|------|------|------|
| V _{CCUV+} V _{BSUV+} | V_{CC} and V_{BS} Supply Under–voltage Positive Going Threshold | | 8.2 | 9.2 | 10.0 | V |
| V _{CCUV-} V _{BSUV-} | V_{CC} and V_{BS} Supply Under–voltage Negative Going Threshold | | 7.6 | 8.7 | 9.6 | |
| V _{CCUVH} V _{BSUVH} | V _{CC} Supply Under–voltage Lockout Hysteresis | | - | 0.6 | - | |
| I _{LK} | Offset Supply Leakage Current | $V_{B} = V_{S} = 200 V$ | - | - | 50 | μΑ |
| I _{QBS} | Quiescent V _{BS} Supply Current | $V_{IN} = 0 V \text{ or } 5 V$ | - | 45 | 120 | |
| I _{QCC} | Quiescent V _{CC} Supply Current | $V_{IN} = 0 V \text{ or } 5 V$ | - | 70 | 180 | |
| I _{PBS} | Operating V _{BS} Supply Current | f _{IN} = 20 kHz, rms value | - | - | 600 | μΑ |
| I _{PCC} | Operating V _{CC} Supply Current | f _{IN} = 20 kHz, rms value | - | - | 600 | |
| VIH | Logic "1" Input Voltage | | 2.9 | - | - | V |
| VIL | Logic "0" Input Voltage | | - | - | 0.8 | |
| V _{OH} | High–level Output Voltage, V_{BIAS} – V_O | I _O = 20 mA | - | - | 1.0 | |
| V _{OL} | Low–level Output Voltage, V_O | | - | - | 0.6 | |
| I _{IN+} | Logic "1" Input Bias Current | V _{IN} = 5 V | - | 10 | 20 | μΑ |
| I _{IN-} | Logic "0" Input Bias Current | V _{IN} = 0 V | - | 1.0 | 2.0 | |
| I _{O+} | Output High Short-circuit Pulsed Current | V_{O} = 0 V, V_{IN} = 5 V with PW < 10 μs | 250 | 350 | - | mA |
| I _{O-} | Output Low Short-circuit Pulsed Current | V_{O} = 15 V, V_{IN} = 0 V with PW < 10 μs | 500 | 650 | - | |
| VS | Allowable Negative V _S Pin Voltage for HIN Signal Propagation to HO | | - | -9.8 | -7.0 | V |

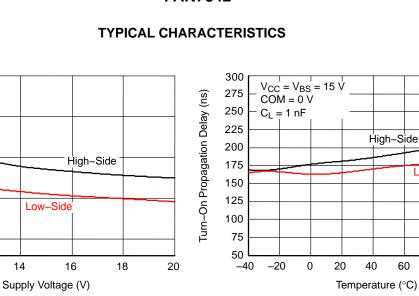
| ELECTRICAL CHARACTERISTICS (V _{BIAS} (V _{CC} , V _{BS}) = 15.0 V, T _A = 25°C, unless otherwise specified. The V _{IN} and I _{IN} parameters are | |
|--|--|
| referenced to COM. The V _O and I _O parameters are referenced to V _S and COM and are applicable to the respective outputs HO and LO.) | |

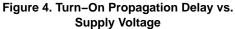
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

DYNAMIC ELECTRICAL CHARACTERISTICS (V_{BIAS} (V_{CC} , V_{BS}) = 15.0 V, V_S = COM, C_L = 1000 pF and, T_A = 25°C, unless otherwise specified.)

| Symbol | Characteristics | Test Condition | Min | Тур | Max | Unit |
|------------------|-------------------------------------|--|-----|-----|-----|------|
| t _{on} | Turn-on Propagation Delay | $V_{S} = 0 V$ | 100 | 170 | 300 | ns |
| t _{off} | Turn-off Propagation Delay | V _S = 0 V or 200 V (Note 4) | 100 | 200 | 300 | ns |
| t _r | Turn-on Rise Time | | 20 | 60 | 140 | ns |
| t _f | Turn-off Fall Time | | - | 30 | 80 | ns |
| MT | Delay Matching, HS & LS Turn-on/off | | - | - | 50 | ns |

4. This parameter guaranteed by design.





300

250

200

150

100

10

Turn-On Propagation Delay (ns)

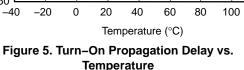
 $V_{CC} = V_{BS}$

COM = 0 V

 $C_L = 1 nF$

 $T_A = 25^{\circ}C$

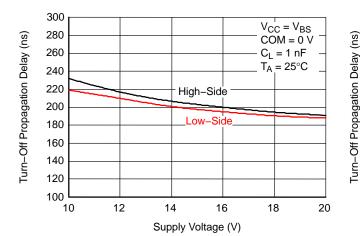
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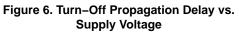


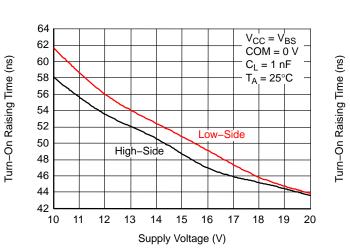
Low-Side

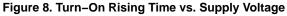
120











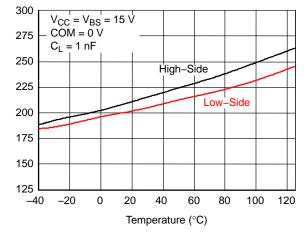
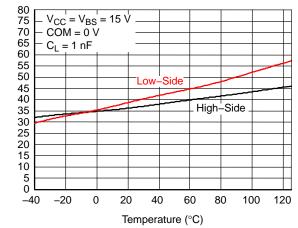
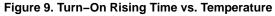
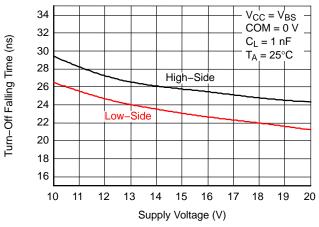


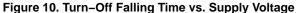
Figure 7. Turn–Off Propagation Delay vs. Temperature





TYPICAL CHARACTERISTICS (CONTINUED)





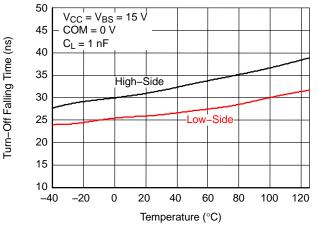
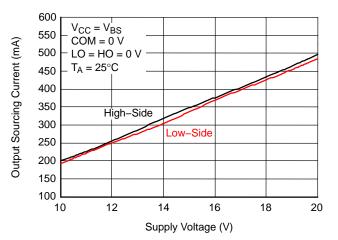
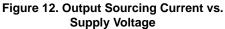


Figure 11. Turn–Off Falling Time vs. Temperature





Output Sinking Current (mA)

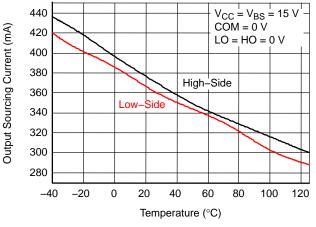
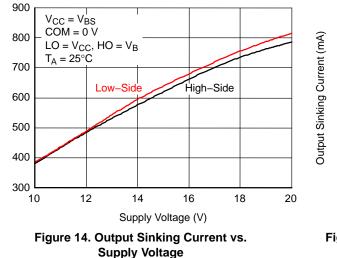


Figure 13. Output Sourcing Current vs. Temperature



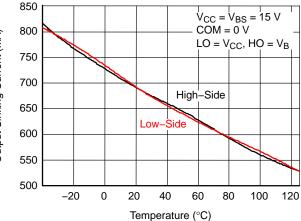
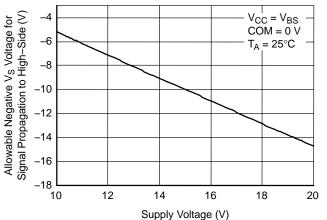


Figure 15. Output Sinking Current vs. Temperature

TYPICAL CHARACTERISTICS (CONTINUED)





100

80

60

40

20

0

0

lacc (µA)

 $V_{BS} = 15 V$

COM = 0 V

 $T_A = 25^{\circ}C$

HIN = LIN = 0 V

5

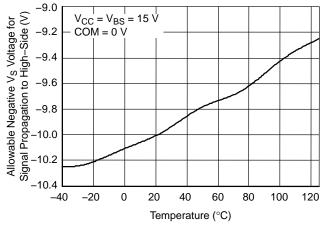
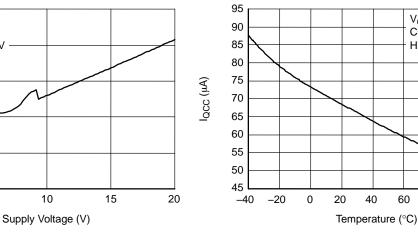
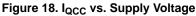


Figure 17. Allowable Negative V_S Voltage for Signal Propagation to High Side vs. Temperature





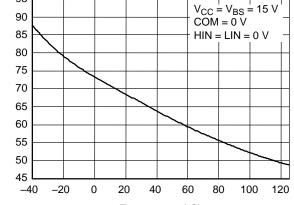
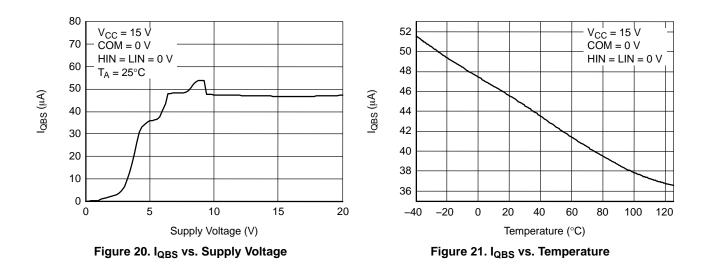
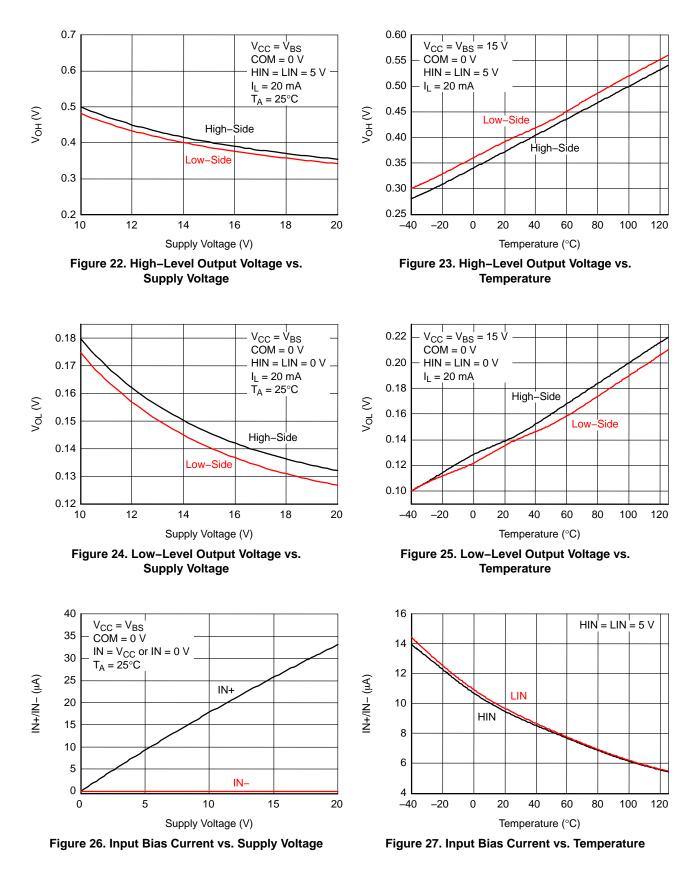


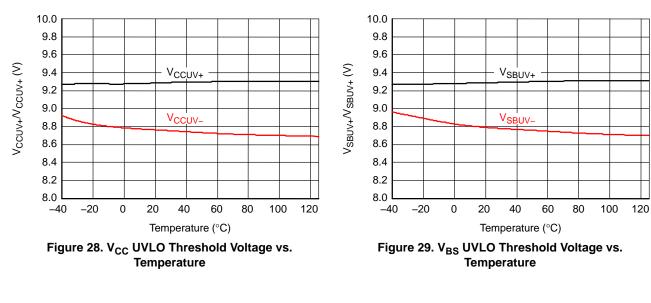
Figure 19. IQCC vs. Temperature



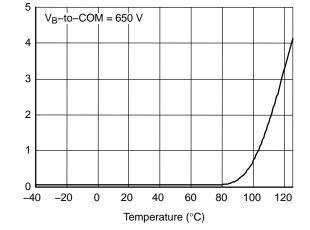
TYPICAL CHARACTERISTICS (CONTINUED)



TYPICAL CHARACTERISTICS (CONTINUED)



Input Logic Threshold Voltage (V)



I_{LK} (μA)



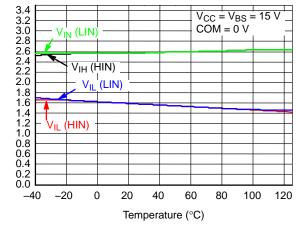


Figure 31. Input Logic Threshold Voltage vs. Temperature

TYPICAL CHARACTERISTICS (CONTINUED)

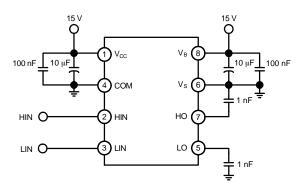


Figure 32. Switching Time Test Circuit

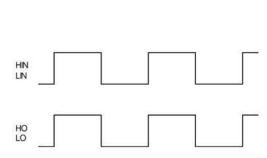


Figure 33. Input / Output Timing Diagram

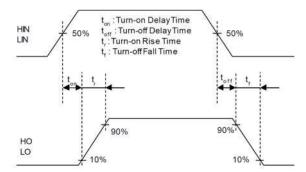


Figure 34. Switching Time Waveform Definition

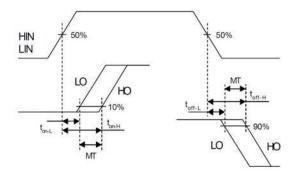


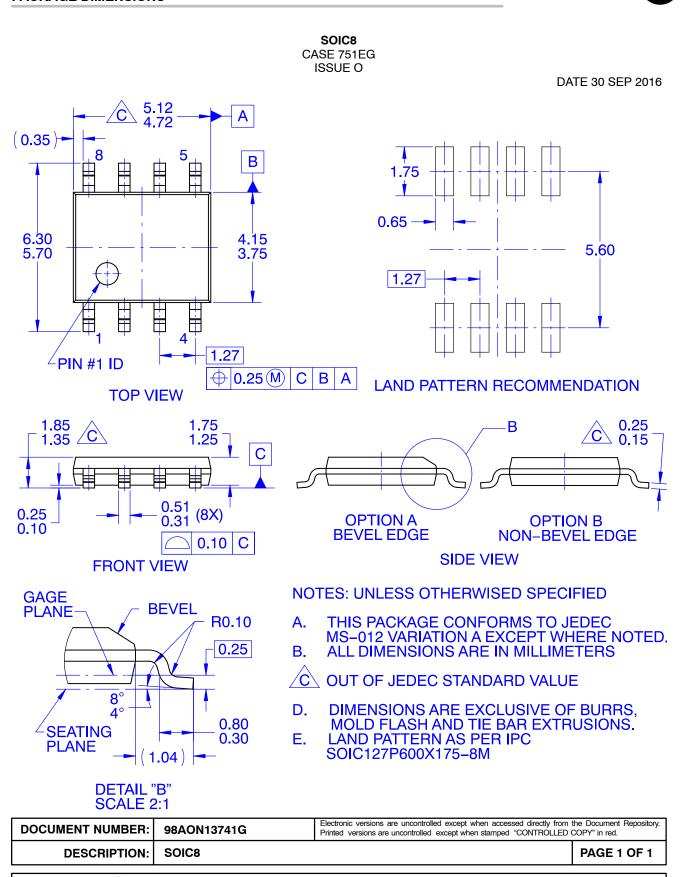
Figure 35. Delay Matching Waveform Definition

ORDERING INFORMATION

| Part Number | Package | Operating Temperature Range | Shipping [†] |
|--------------------|---|-----------------------------|-----------------------|
| FAN7842MX (Note 5) | SOIC8 (8–SOP) (Pb–Free, Halide Free) | –40°C∼125°C | 3000 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

5. These devices passed wave soldering test by JESD22A-111.



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